

Supporting Information

Multifunctional Applications Enabled by Tunable Multi-Emission and Ultra-Broadband Vis-NIR Luminescence via Energy Transfer in Sn²⁺/Mn²⁺-Doped Lead-Free Zn- Based Metal Halides

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Table S1. Single crystal X-ray diffraction data of (TPA)₂ZnBr₄.

Empirical formula	(TPA) ₂ ZnBr ₄
Chemical formula	C ₂₄ H ₅₆ Br ₄ N ₂ Zn
Formula weight	757.72
Temperature (K)	296(2)
Crystal system	monoclinic
Space group	C2/c
a (Å)	33.145(5)
b (Å)	14.234(3)
c (Å)	15.081(2)
α (deg)	90
β (deg)	110.207(5)
γ (deg)	90
Volume (Å³)	6677.1(17)
Z	8

Table S2. PL decay parameters of (TPA)₂ZnBr₄:Sn²⁺/Mn²⁺ monitored at 510 nm emission wavelength with different doping concentration of Sn²⁺.

Sn ²⁺ content	τ ₁ (μs)	τ ₂ (μs)	τ _{ave} (μs)
0%	0	364.9	361.2
1%	4.58	357.0	356.9
5%	4.68	351.8	351.8
10%	4.75	347.0	346.9
15%	4.81	336.8	336.2
20%	4.85	320.8	320.0
25%	5.54	275.4	270.0

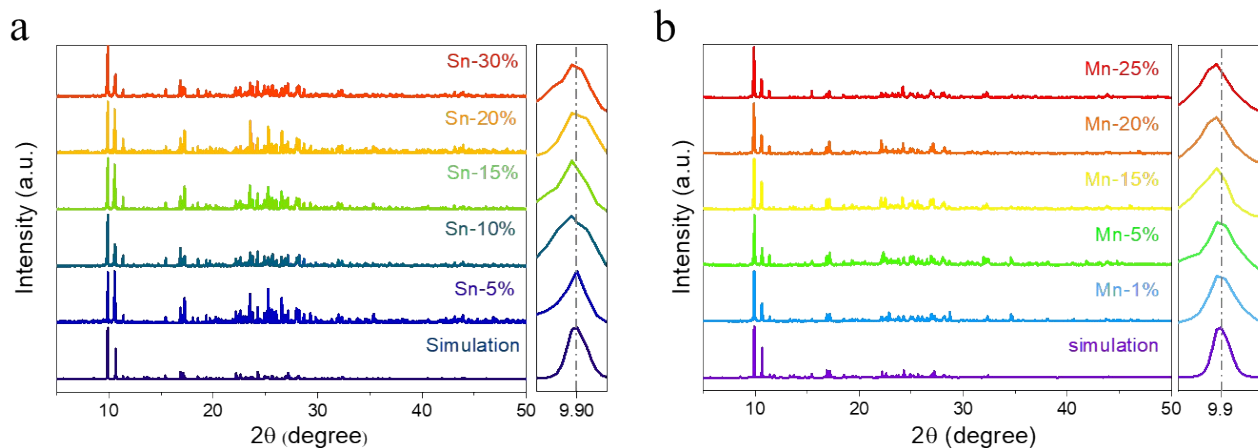


Fig. S1. PXRD patterns of (TPA)₂ZnBr₄:x%Sn²⁺ (a) and (TPA)₂ZnBr₄:x%Mn²⁺ (b).

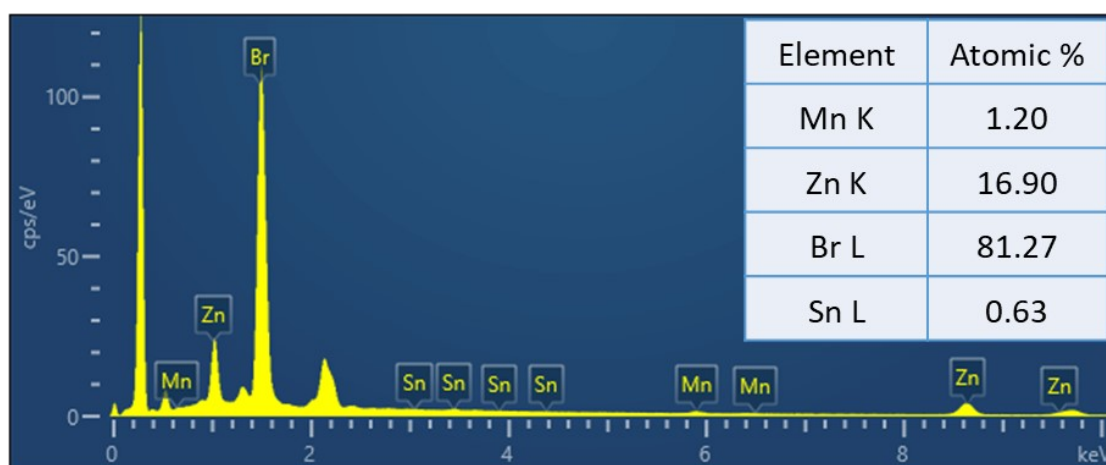


Fig. S2. EDS spectrum and element proportion in the (TPA)₂ZnBr₄:5%Sn²⁺/20%Mn²⁺ SCs, the inset table shows the element ratio.

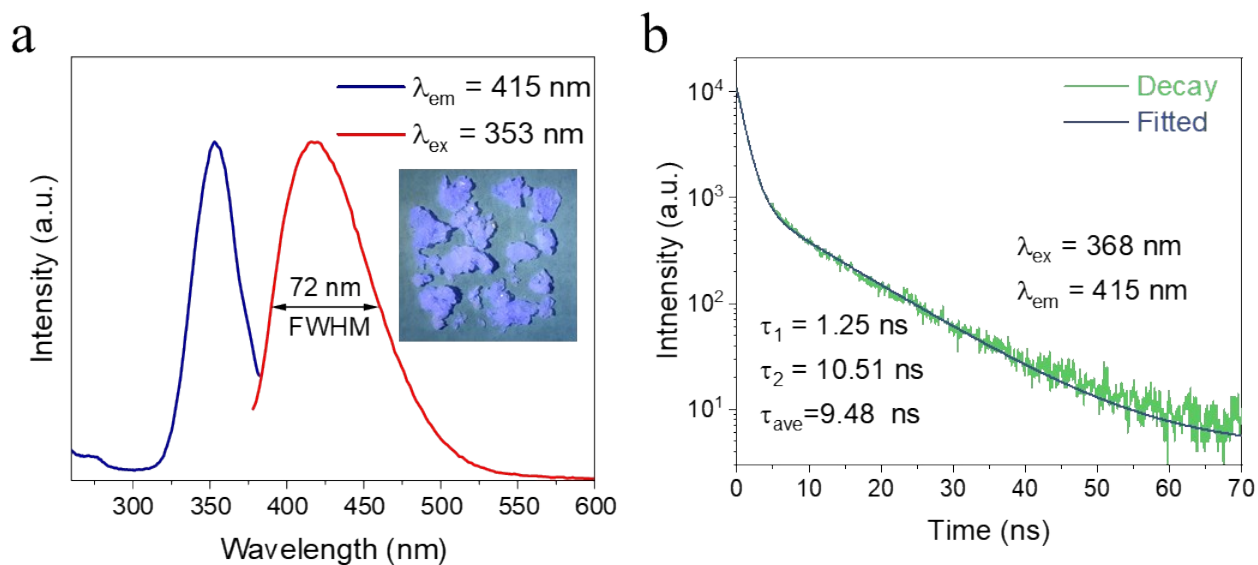


Fig. S3. (a) Normalized PLE and PL spectra of $(\text{TPA})_2\text{ZnBr}_4$ ($\lambda_{\text{ex}} = 353$ nm, $\lambda_{\text{em}} = 415$ nm). Inset image shows the $(\text{TPA})_2\text{ZnBr}_4$ at 365 nm excitation. (b) PL decay curves of $(\text{TPA})_2\text{ZnBr}_4$ ($\lambda_{\text{ex}} = 368$ nm, $\lambda_{\text{em}} = 415$ nm).

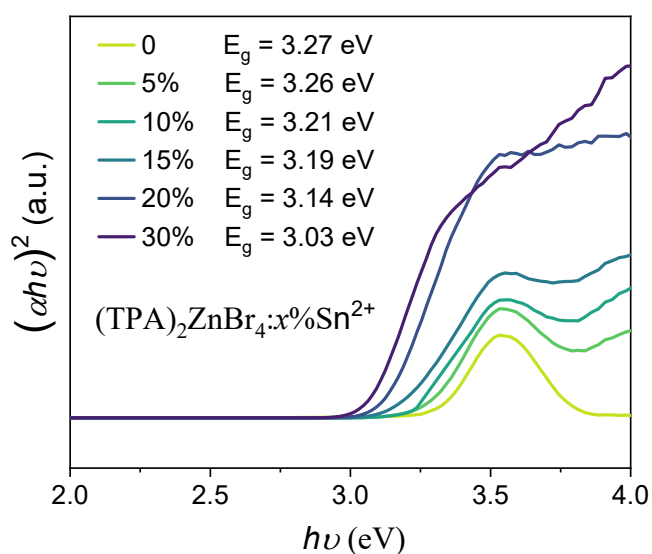


Fig. S4. Tauc plots of the diffuse reflectance spectra of recrystallized $(\text{TPA})_2\text{ZnBr}_4:x\%\text{Sn}^{2+}$. The optical bandgaps (E_g) of the as-prepared samples were calculated by using the Kubelka–Munk theory¹:

$$[F(R_\infty)hv]^n = A(hv - E_g)$$

where R is the reflectance coefficient (%), $h\nu$ represents the photon energy, and A represents the absorption constant.

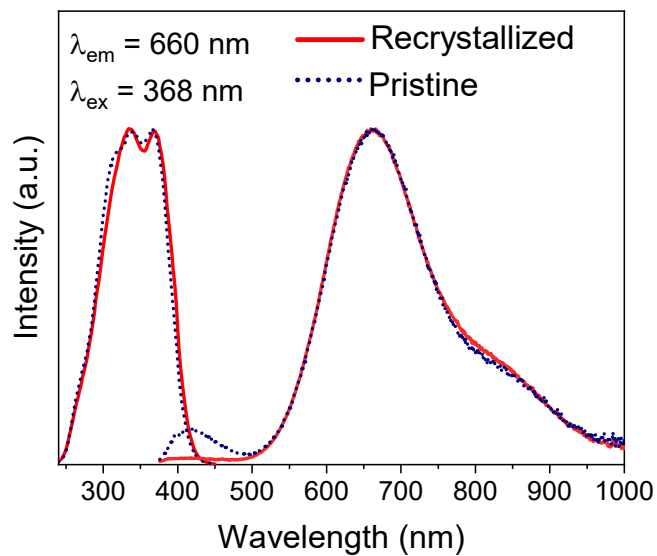


Fig. S5. Normalized PL and PLE spectra of pristine (blue) and recrystallized $(\text{TPA})_2\text{ZnBr}_4:20\%\text{Sn}^{2+}$ (red).

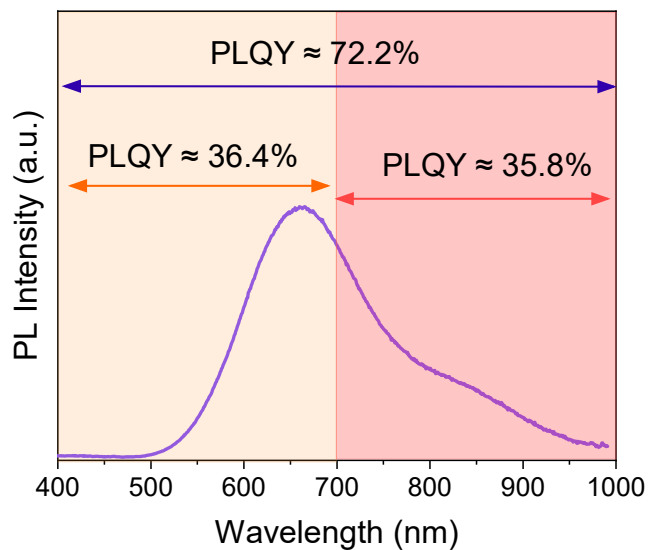


Fig. S6. PL spectra of recrystallized $(\text{TPA})_2\text{ZnBr}_4:20\%\text{Sn}^{2+}$ SCs under the excitation of 368 nm. The PLQY of NIR (700–1000 nm) region, and PLQY of the complete broadband spectral region.

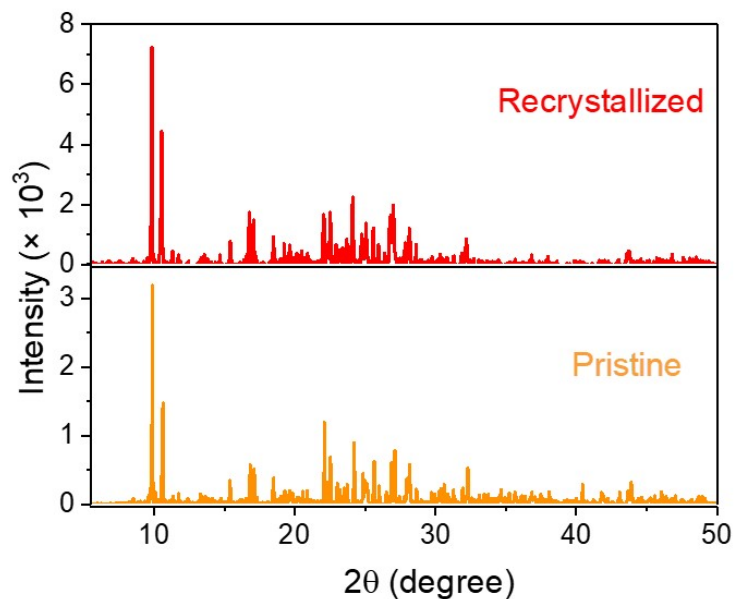


Fig. S7. XRD patterns of the pristine and Recrystallized $(\text{TPA})_2\text{ZnBr}_4:\text{Sn}^{2+}$.

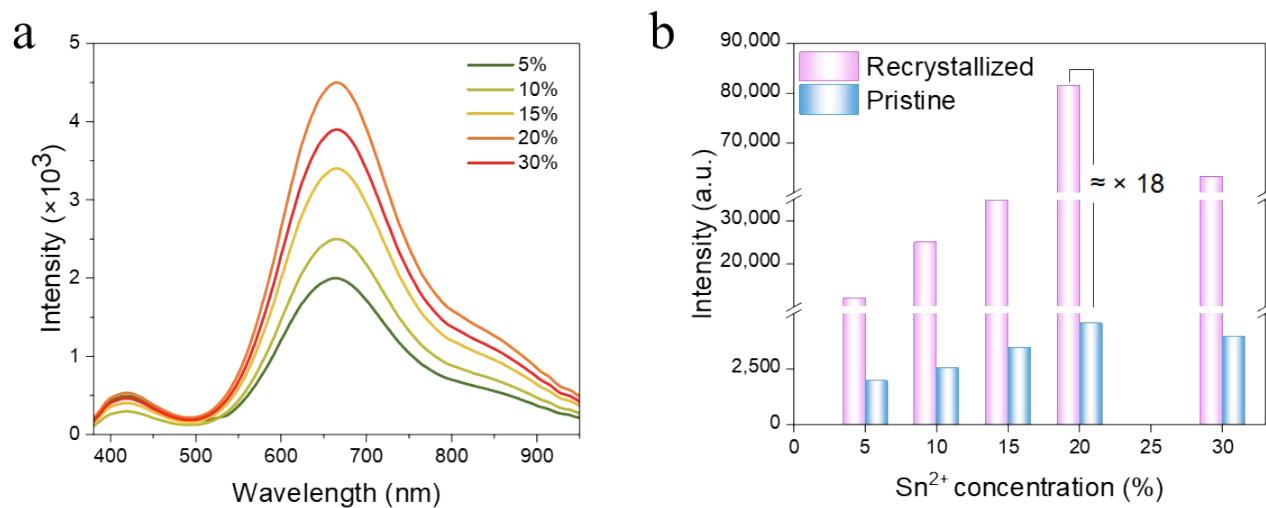


Fig. S8. (a) PL spectra of $(\text{TPA})_2\text{ZnBr}_4:x\%\text{Sn}^{2+}$ with different Sn^{2+} concentrations ($\lambda_{\text{ex}} = 368 \text{ nm}$). **(b)** PL intensity of the pristine and recrystallized $(\text{TPA})_2\text{ZnBr}_4: x\%\text{Sn}^{2+}$ with different Sn^{2+} concentrations.

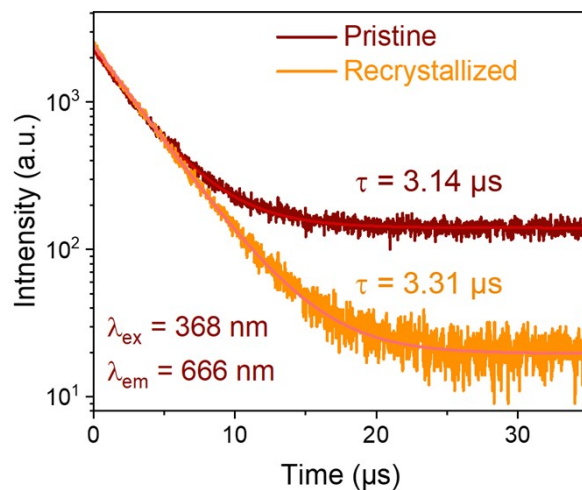


Fig. S9. PL decay curves obtained for the pristine and recrystallized $(\text{TPA})_2\text{ZnBr}_4:20\%\text{Sn}^{2+}$.

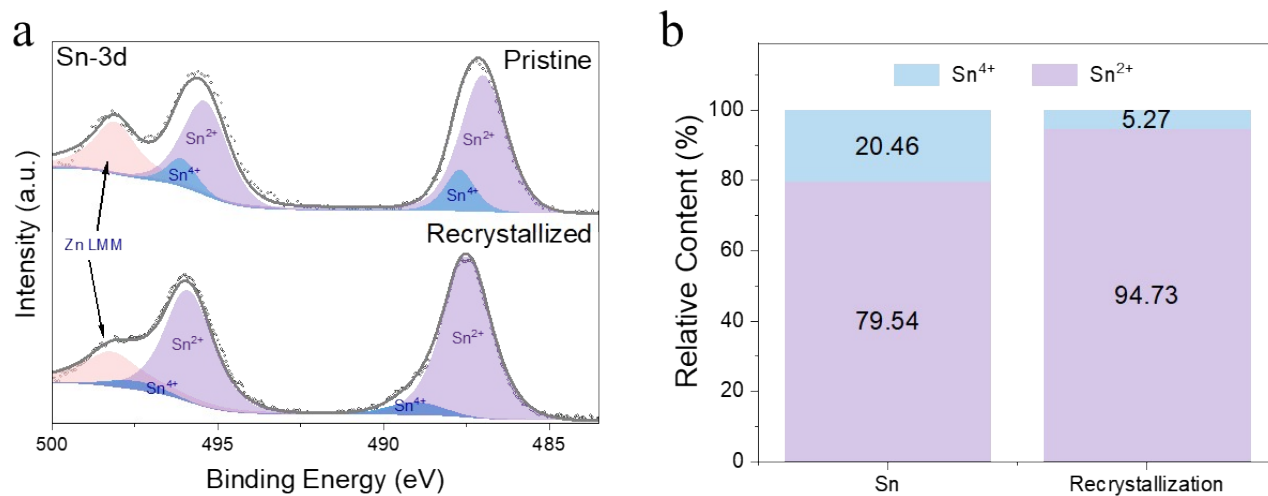


Fig. S10. (a) XPS of Sn 3d spectra. The first peak on the left (pink) is the satellite peak of Zn. **(b)** Proportion of Sn with different valences for the pristine and recrystallized $(\text{TPA})_2\text{ZnBr}_4:20\%\text{Sn}^{2+}$.

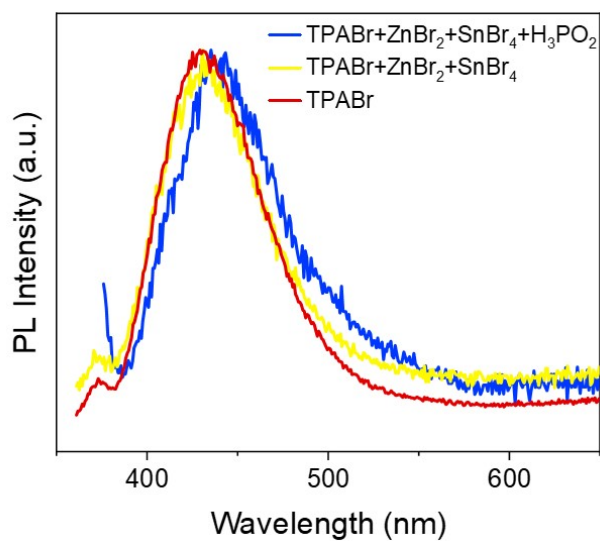


Fig. S11. PL spectra of TPABr and compounds synthesized used SnBr₄.

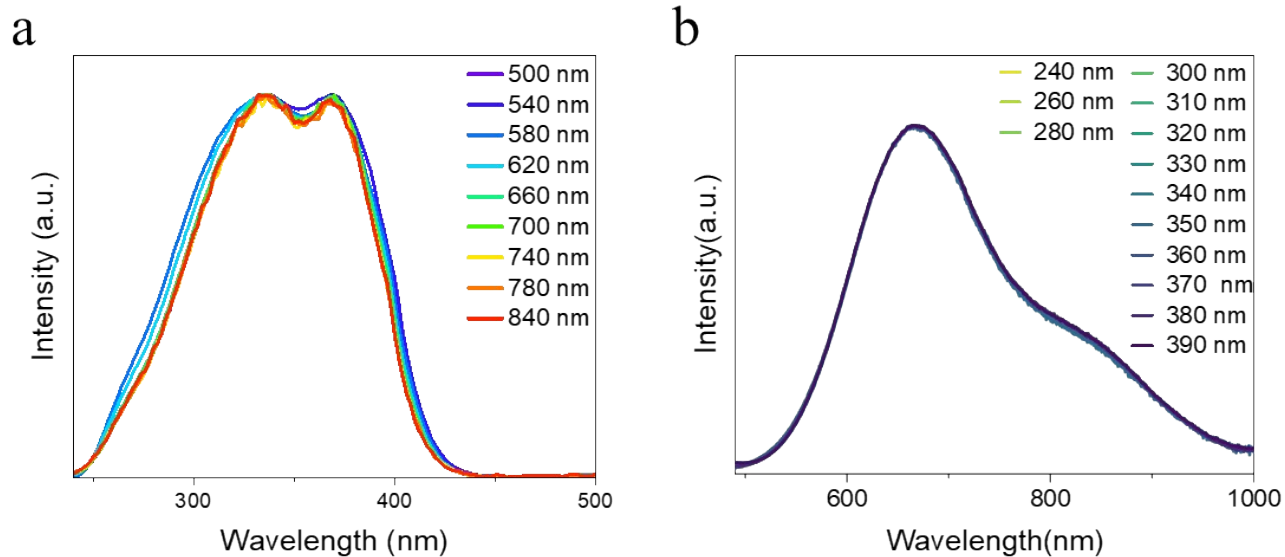


Fig. S12. (a) Emission wavelength-dependent PLE spectra, **(b)** Excitation wavelength-dependent PL spectra of recrystallized (TPA)₂ZnBr₄:20%Sn²⁺ SCs at RT.

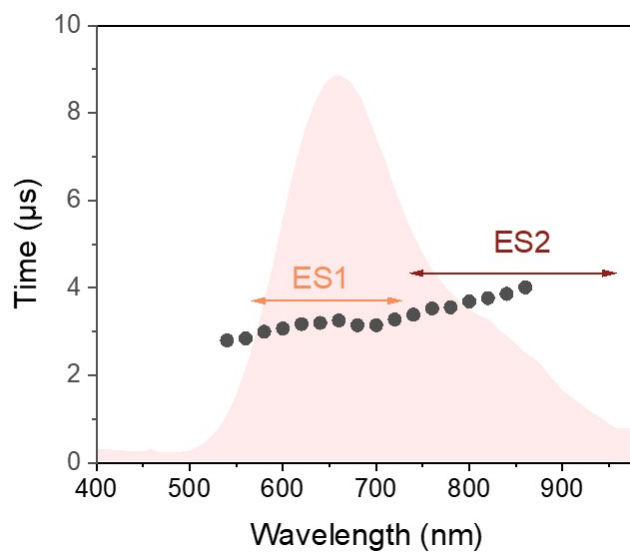


Fig. S13. PL lifetimes at the corresponding wavelengths of recrystallized $(\text{TPA})_2\text{ZnBr}_4:20\%\text{Sn}^{2+}$.

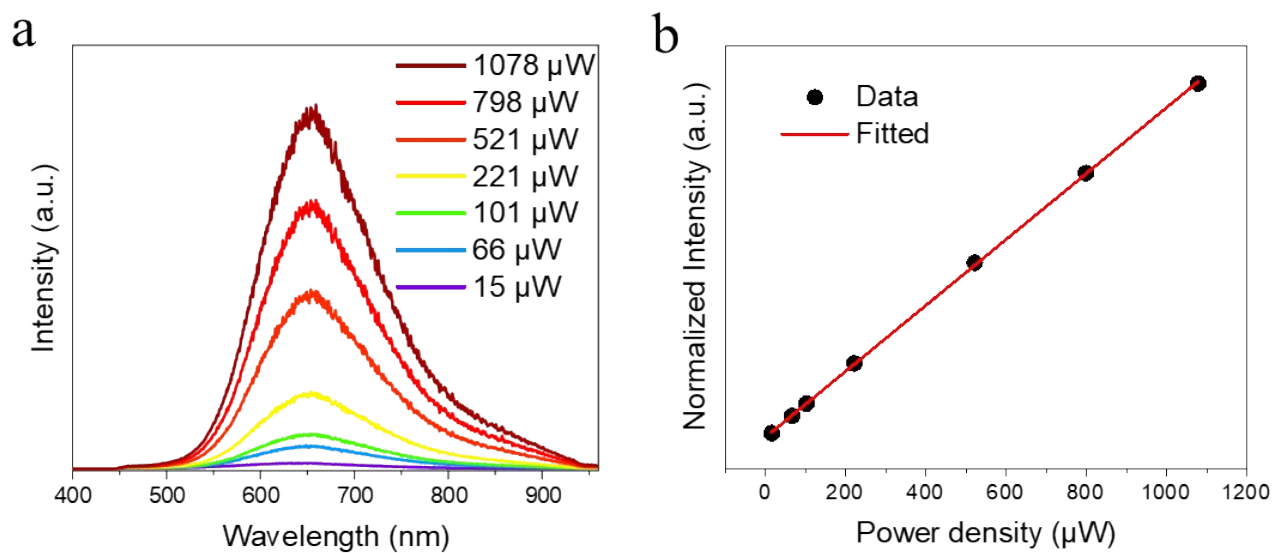


Fig. S14. (a) Excitation power-dependent PL spectra of recrystallized $(\text{TPA})_2\text{ZnBr}_4:20\%\text{Sn}^{2+}$ under 405 nm laser excitation. **(b)** Fitting results of PL intensity versus excitation power.

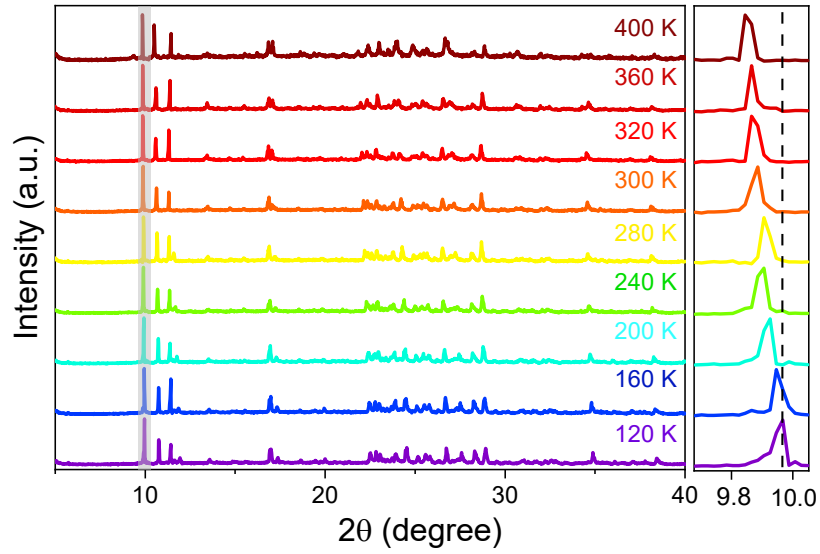


Fig. S15. Temperature-dependent XRD spectra of recrystallized $(\text{TPA})_2\text{ZnBr}_4:20\%\text{Sn}^{2+}$.

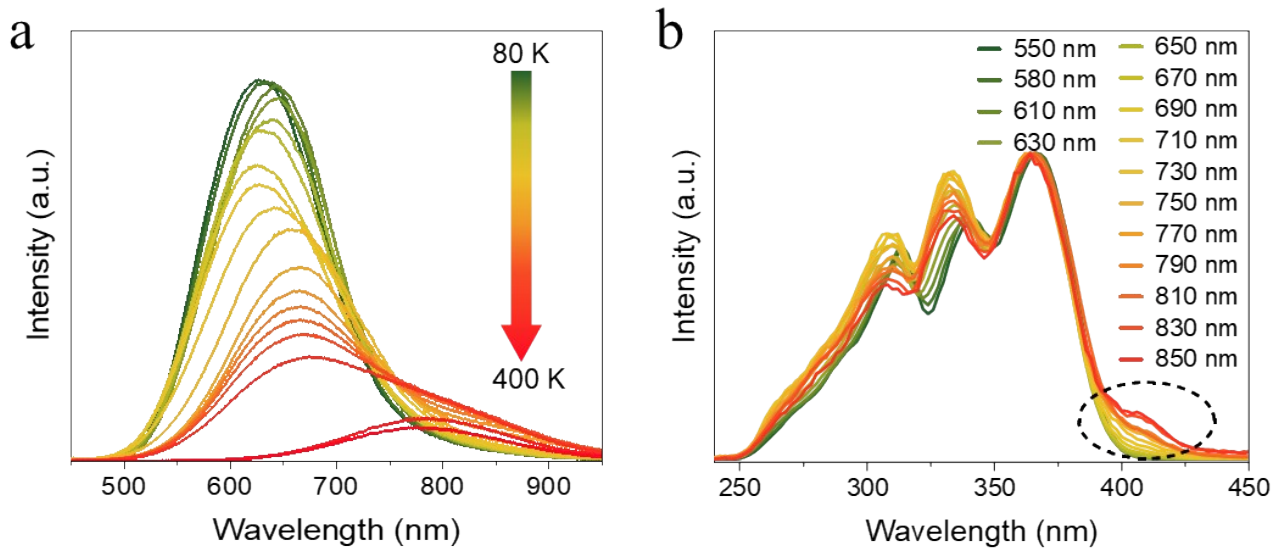


Fig. S16. (a) Temperature dependent PL spectra of recrystallized $(\text{TPA})_2\text{ZnBr}_4:20\%\text{Sn}^{2+}$ intervals of 20 K at 368 nm excitation. (b) Emission wavelength-dependent PLE spectra of recrystallized $(\text{TPA})_2\text{ZnBr}_4:20\%\text{Sn}^{2+}$ at 80 K.

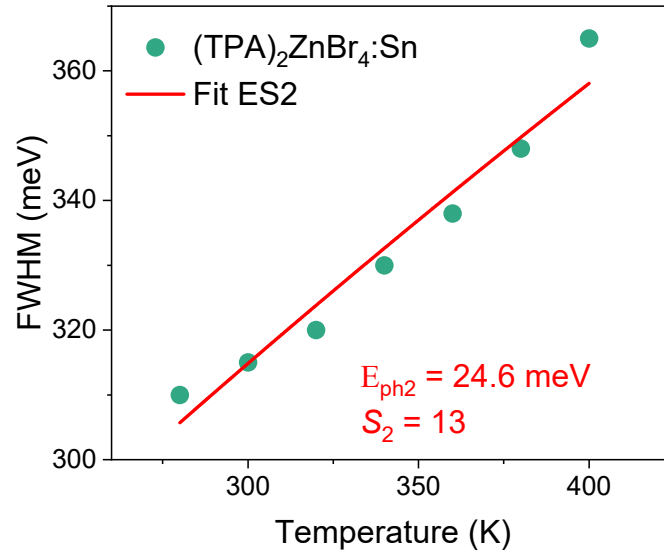


Fig. S17. The fitting result of the function that FWHM of ES2 versus the temperature.

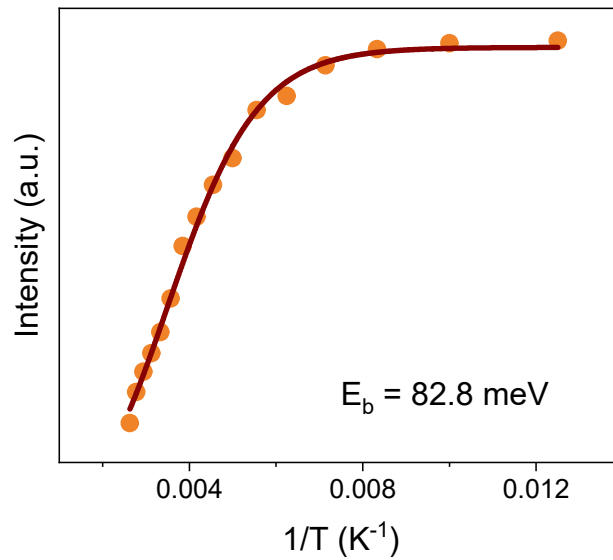


Fig. S18. The fitting result of the function that PL intensity versus the reciprocal of the temperature for (TPA)₂ZnBr₄:20%Sn²⁺.

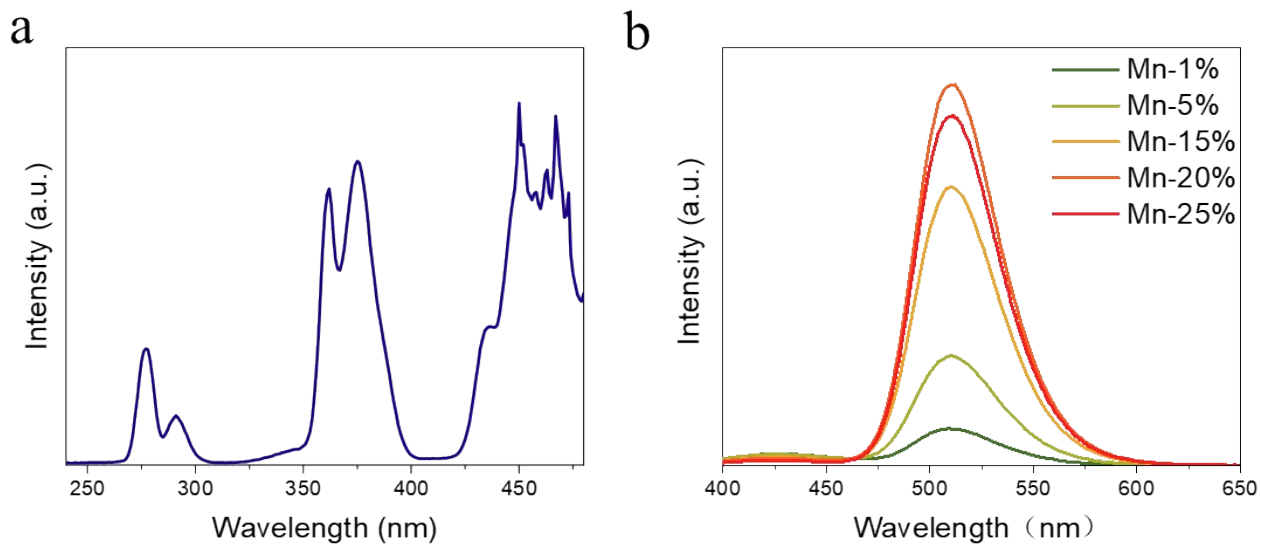


Fig. S19. (a) PLE spectra of $(\text{TPA})_2\text{ZnBr}_4:\text{Mn}^{2+}$. (b) PL spectra ($\lambda_{\text{ex}} = 368 \text{ nm}$) of $(\text{TPA})_2\text{ZnBr}_4:x\%\text{Mn}^{2+}$ with different Mn^{2+} concentrations.

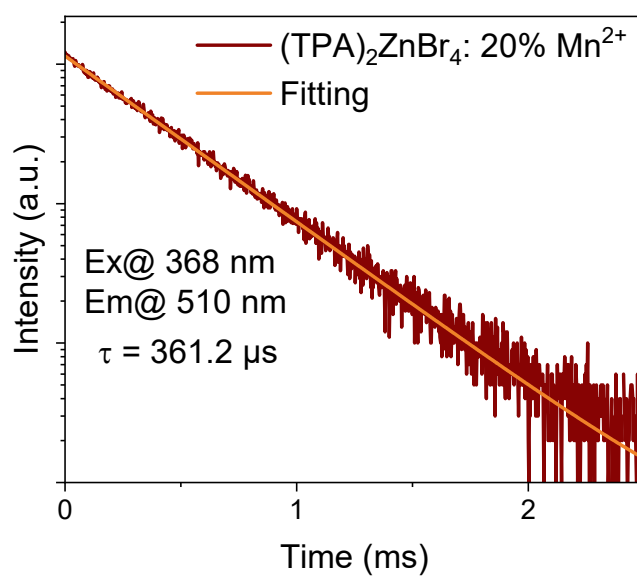


Fig. S20. PL decay curves of $(\text{TPA})_2\text{ZnBr}_4:20\%\text{Mn}^{2+}$ ($\lambda_{\text{ex}} = 368 \text{ nm}$, $\lambda_{\text{em}} = 510 \text{ nm}$).

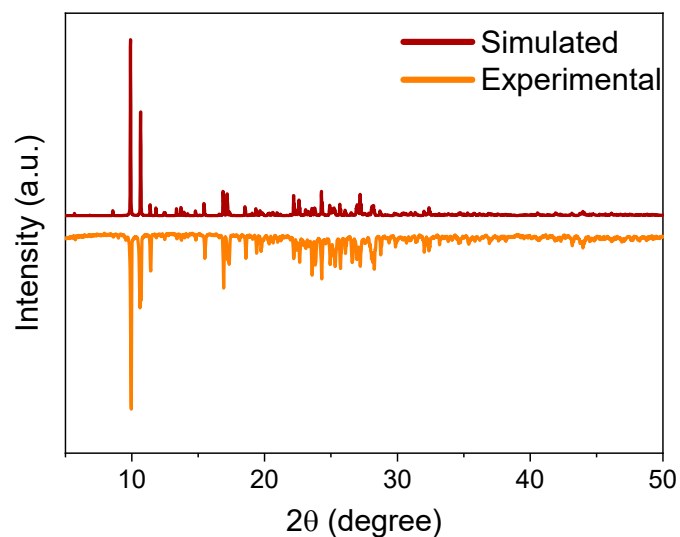


Fig. S21. Experimental and simulated PXRD patterns of $(\text{TPA})_2\text{ZnBr}_4:5\%\text{Sn}^{2+}/20\%\text{Mn}^{2+}$.

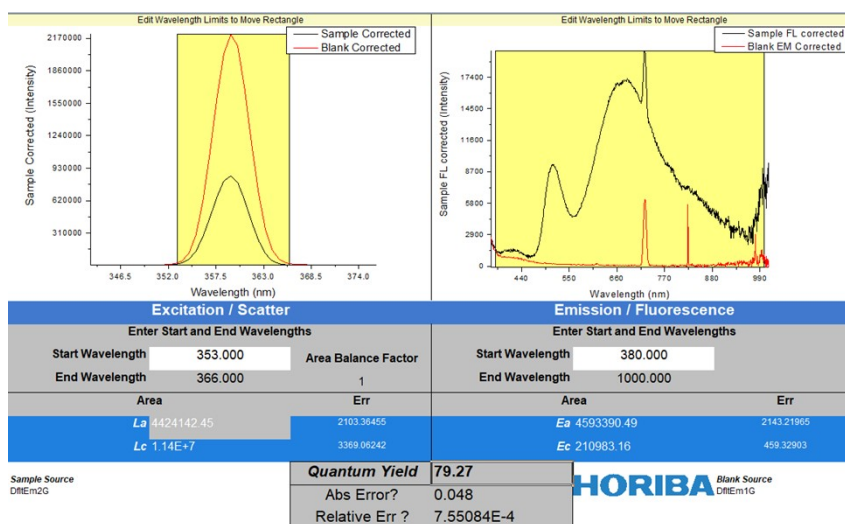


Fig. S22. The maximum PLQY of $(\text{TPA})_2\text{ZnBr}_4: x\%\text{Sn}^{2+}/20\%\text{Mn}^{2+}$ SCs.

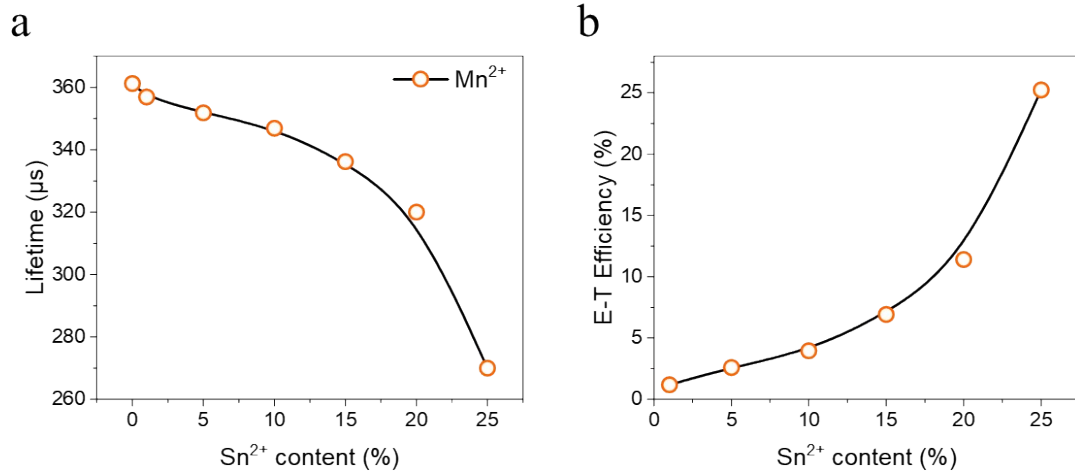


Fig. S23. (a) Lifetime of Mn²⁺ in (TPA)₂ZnBr₄:x%Sn²⁺/20%Mn²⁺ ($\lambda_{\text{ex}} = 368 \text{ nm}$, $\lambda_{\text{em}} = 510 \text{ nm}$). **(b)** Energy transfer efficiency of (TPA)₂ZnBr₄:x%Sn²⁺/20%Mn²⁺.²

$$\eta_{ET} = 1 - \frac{\tau_x}{\tau_0}$$

where τ_0 is the decay lifetime of STE in (TPA)₂ZnBr₄:20% Mn²⁺, τ_x is the decay lifetime of STE in (TPA)₂ZnBr₄:x%Sn²⁺/20%Mn²⁺ with various Sn²⁺ concentrations.

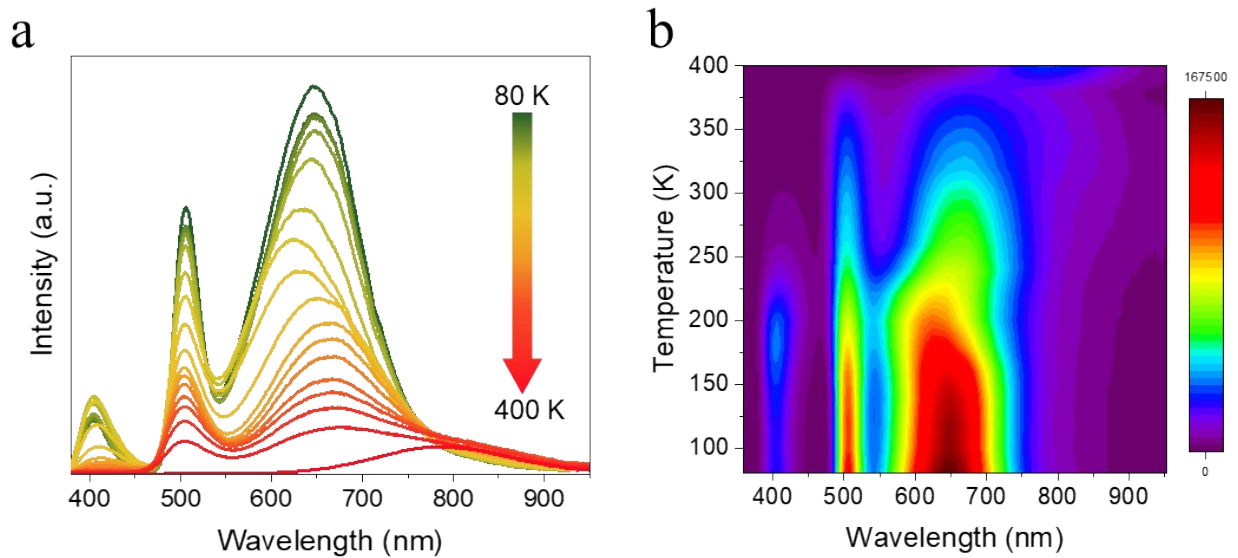


Fig. S24. (a) Temperature-dependent PL spectra of (TPA)₂ZnBr₄:10%Sn²⁺/20%Mn²⁺ excited at 368 nm and corresponding pseudo-color mapping **(b)**.

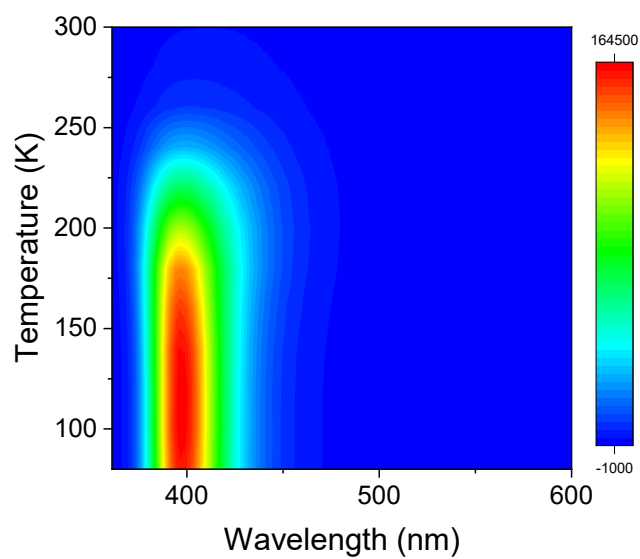


Fig. S25. Temperature-dependent PL spectra of pure $(\text{TPA})_2\text{ZnBr}_4$ excited at 368 nm.

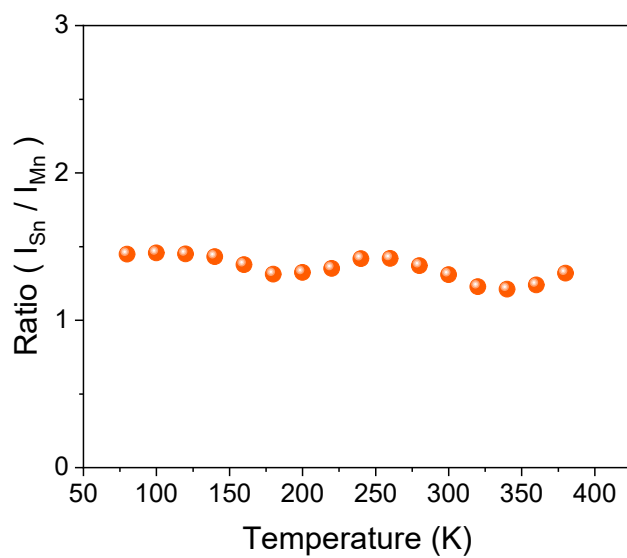


Fig. S26. PL intensity ratio of Sn^{2+} to Mn^{2+} in $(\text{TPA})_2\text{ZnBr}_4:10\%\text{Sn}^{2+}/20\%\text{Mn}^{2+}$ as a function of temperature.

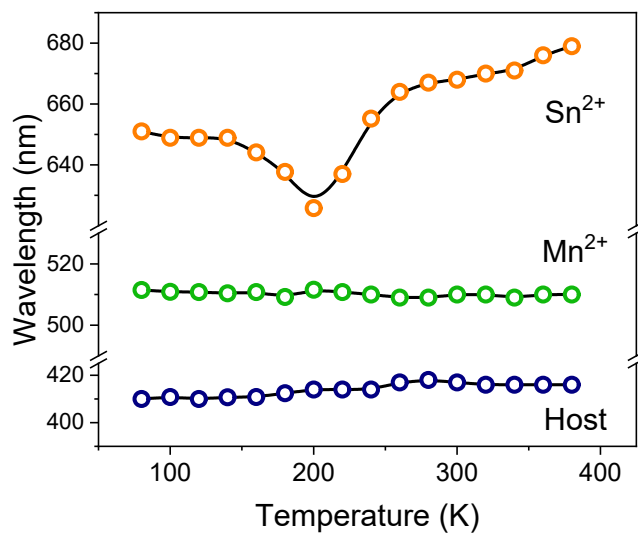


Fig. S27. PL peak position of $(\text{TPA})_2\text{ZnBr}_4:10\%\text{Sn}^{2+}/20\%\text{Mn}^{2+}$ under various temperature.

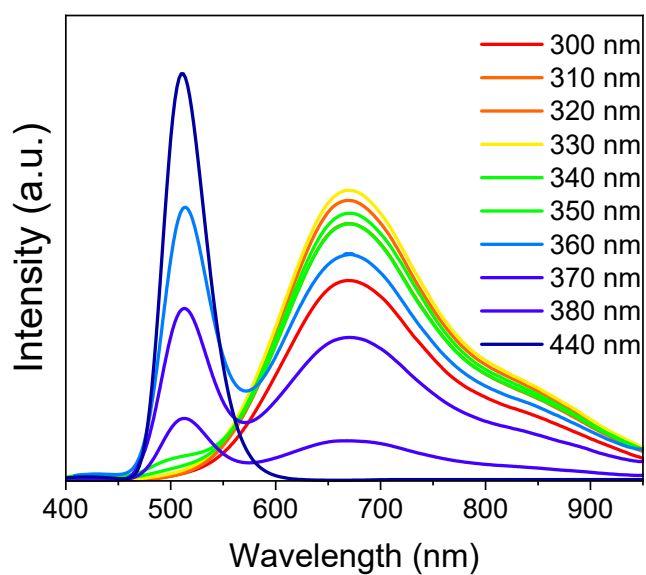


Fig. S28. Excitation wavelength-dependent PL spectra of $(\text{TPA})_2\text{ZnBr}_4:5\%\text{Sn}^{2+}/20\%\text{Mn}^{2+}\text{SCs}$.

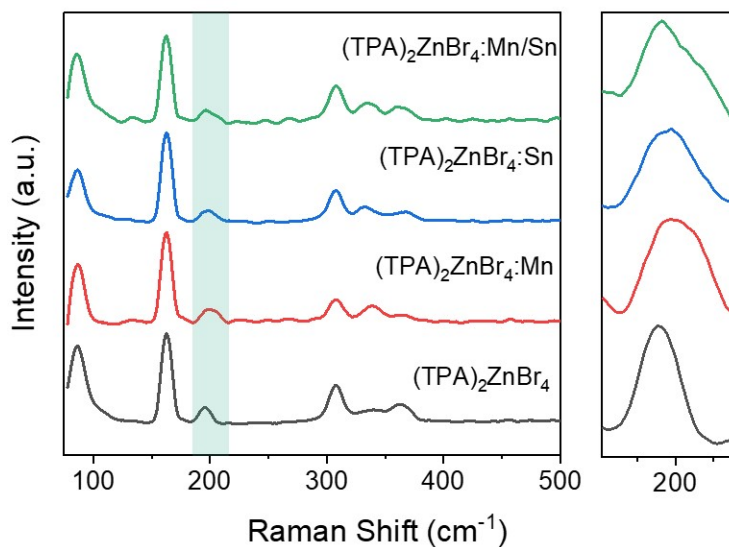


Fig. S29. Raman spectra of pure, Mn²⁺-doped, Sn²⁺-doped, and Mn²⁺/Sn²⁺-codoped (TPA)₂ZnBr₄.

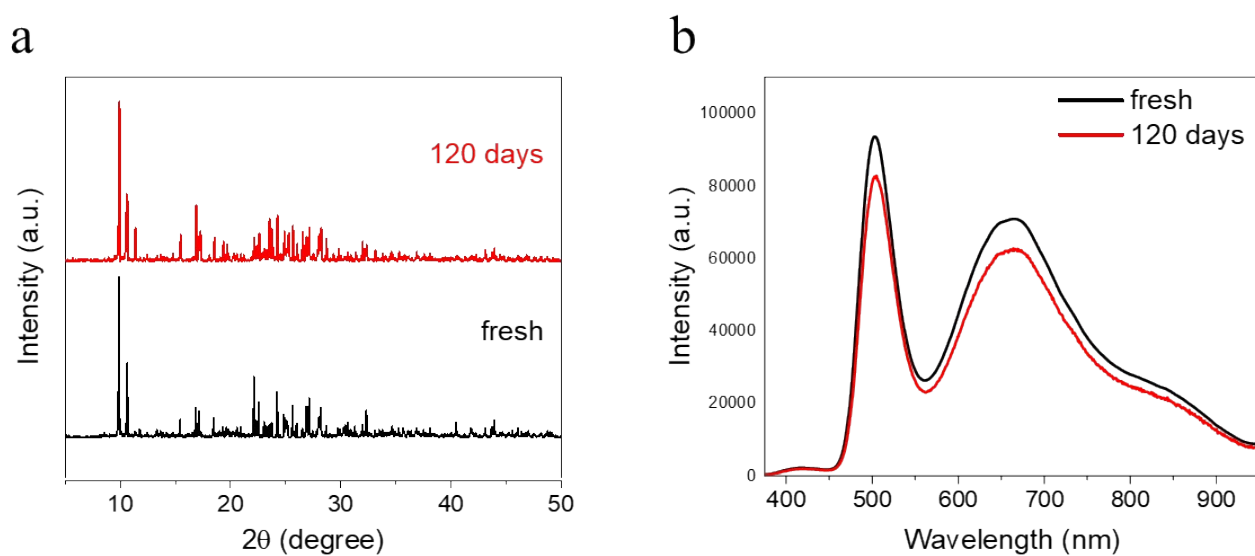


Fig. S30. XRD patterns (a) and PL spectra (b) of (TPA)₂ZnBr₄:5% Sn²⁺/20%Mn²⁺ stored in atmospheric environment for 120 days.

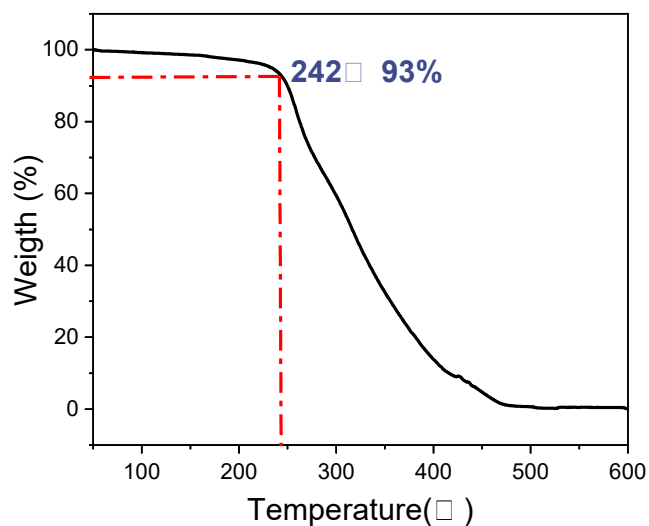


Fig. S31. TG curves of $(\text{TPA})_2\text{ZnBr}_4:5\% \text{Sn}^{2+}/20\%\text{Mn}^{2+}$ powders.

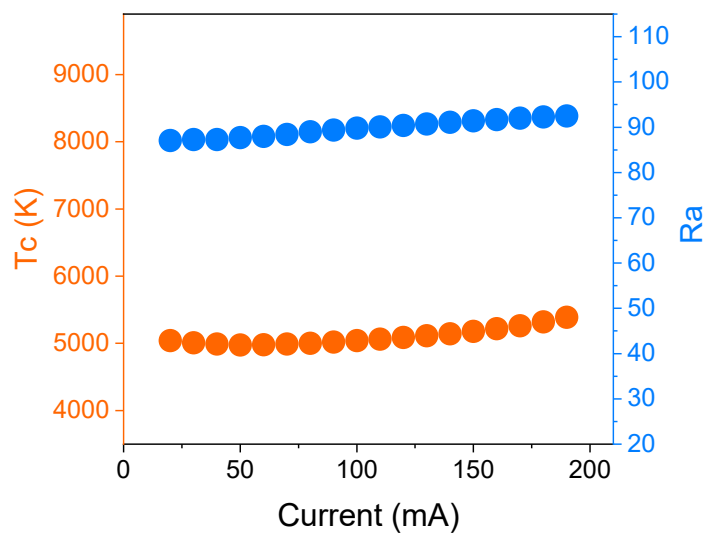


Fig. S32. CRI and CCT stability of the pc-LED device by mixing $(\text{TPA})_2\text{ZnBr}_4:5\%\text{Sn}^{2+}/20\%\text{Mn}^{2+}$ powders with PMMA polymer at various operating currents.

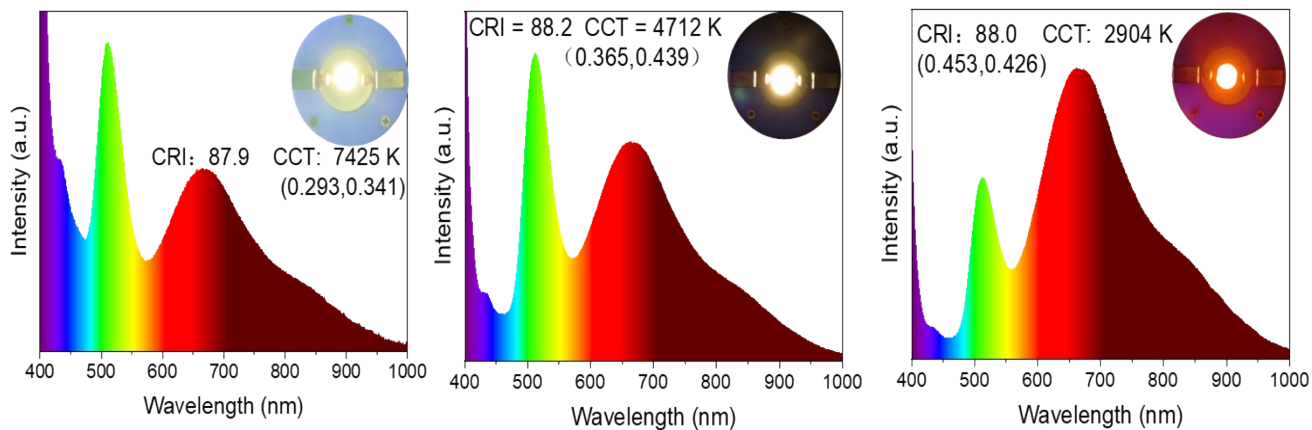


Fig. S33. EL spectra of $(\text{TPA})_2\text{ZnBr}_4:x\%\text{Sn}^{2+}/20\%\text{Mn}^{2+}$ pc-LEDs at 60 mA drive current with various Sn^{2+} concentrations, the inset shows the optical photos of the operating pc-LEDs.

REFERENCES

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- 2 L. Cao, X. Jia, W. Gan, C.-G. Ma, J. Zhang, B. Lou and J. Wang, *Adv. Funct. Mater*, 2023, **33**, 2212135.